SCAS870F - FEBRUARY 2009 - REVISED JUNE 2011



# Two Output, Integrated VCO, Low-Jitter Clock Generator

Check for Samples: CDCM61002

#### **FEATURES**

- One Crystal/LVCMOS Reference Input Including 24.8832 MHz, 25 MHz, and 26.5625 MHz
- Input Frequency Range: 21.875 MHz to 28.47 MHz
- On-Chip VCO Operates in Frequency Range of 1.75 GHz to 2.05 GHz
- 2x Output Available:
  - Pin-Selectable Between LVPECL, LVDS, or 2-LVCMOS; Operates at 3.3 V
- LVCMOS Bypass Output Available
- Output Frequency Selectable by /1, /2, /3, /4, /6, /8 from a Single Output Divider
- Supports Common LVPECL/LVDS Output Frequencies:
  - 62.5 MHz, 74.25 MHz, 75 MHz, 77.76 MHz, 100 MHz, 106.25 MHz, 125 MHz, 150 MHz, 155.52 MHz, 156.25 MHz, 159.375 MHz, 187.5 MHz, 200 MHz, 212.5 MHz, 250 MHz, 311.04 MHz, 312.5 MHz, 622.08 MHz, 625 MHz
- Supports Common LVCMOS Output Frequencies:
  - 62.5 MHz, 74.25 MHz, 75 MHz, 77.76 MHz,
     100 MHz, 106.25 MHz, 125 MHz, 150 MHz,
     155.52 MHz, 156.25 MHz, 159.375 MHz,
     187.5 MHz, 200 MHz, 212.5 MHz, 250 MHz
- Output Frequency Range: 43.75 MHz to 683.264 MHz (See Table 3)
- Internal PLL Loop Bandwidth: 400 kHz
- High-Performance PLL Core:
  - Phase Noise typically at –146 dBc/Hz at 5-MHz Offset for 625-MHz LVPECL Output
  - Random Jitter typically at 0.509 ps, RMS (10 kHz to 20 MHz) for 625-MHz LVPECL Output
- Output Duty Cycle Corrected to 50% (± 5%)
- Low Output Skew of 20 ps on LVPECL Outputs

- Divider Programming Using Control Pins:
  - Two Pins for Prescaler/Feedback Divider
  - Three Pins for Output Divider
  - Two Pins for Output Select
- Chip Enable Control Pin Available
- 3.3-V Core and I/O Power Supply
- Industrial Temperature Range: –40°C to +85°C
- 5-mm × 5-mm, 32-pin, QFN (RHB) Package
- ESD Protection Exceeds 2 kV (HBM)

#### **APPLICATIONS**

- Low Jitter Clock Driver for High-End Datacom Applications Including SONET, Ethernet, Fibre Channel, Serial ATA, and HDTV
- Cost-Effective High-Frequency Crystal Oscillator Replacement

#### DESCRIPTION

The CDCM61002 is a highly versatile, low-jitter frequency synthesizer that can generate two low-jitter clock outputs, selectable between low-voltage positive emitter coupled logic (LVPECL), low-voltage differential signaling (LVDS), or low-voltage complementary metal oxide semiconductor (LVCMOS) outputs, from a low-frequency crystal or LVCMOS input for a variety of wireline and data The CDCM61002 communication applications. features an onboard PLL that can be easily configured solely through control pins. The overall output random jitter performance is less than 1ps, RMS (from 10 kHz to 20 MHz), making this device a perfect choice for use in demanding applications such as SONET, Ethernet, Fibre Channel, and SAN. The CDCM61002 is available in a small, 32-pin, 5-mm × 5-mm QFN package.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### **DESCRIPTION, CONTINUED**

The CDCM61002 is a high-performance, low phase noise, fully-integrated voltage-controlled oscillator (VCO) clock synthesizer with two universal output buffers that can be configured to be LVPECL, LVDS, or LVCMOS compatible. Each universal output can also be converted to two LVCMOS outputs. Additionally, an LVCMOS bypass output clock is available in an output configuration which can help with crystal loading in order to achieve an exact desired input frequency. It has one fully-integrated, low-noise, LC-based VCO that operates in the 1.75 GHz to 2.05 GHz range.

The phase-locked loop (PLL) synchronizes the VCO with respect to the input, which can either be a low-frequency crystal. The outputs share an output divider sourced from the VCO core. All device settings are managed through a control pin structure, which has two pins that control the prescaler and feedback divider, three pins that control the output divider, two pins that control the output type, and one pin that controls the output enable. Any time the PLL settings (including the input frequency, prescaler divider, or feedback divider) are altered, a reset must be issued through the Reset control pin (active low for device reset). The reset initiates a PLL recalibration process to ensure PLL lock. When the device is in reset, the outputs and dividered are turned off.

The output frequency  $(f_{OUT})$  is proportional to the frequency of the input clock  $(f_{IN})$ . The feedback divider, output divider, and VCO frequency set  $f_{OUT}$  with respect to  $f_{IN}$ . For a configuration setting for common wireline and datacom applications, refer to Table 2. For other applications, use Equation 1 to calculate the exact crystal oscillator frequency required for the desired output.

$$f_{IN} = \left(\frac{\text{Output Divider}}{\text{Feedback Divider}}\right) f_{OUT}$$
(1)

The output divider can be chosen from 1, 2, 3, 4, 6, or 8 through the use of control pins. Feedback divider and prescaler divider combinations can be chosen from 25 and 3, 24 and 3, 20 and 4, or 15 and 5, respectively, also through the use of control pins. Figure 1 shows a high-level block diagram of the CDCM61002.

The device operates in a 3.3-V supply environment and is characterized for operation from -40°C to +85°C.

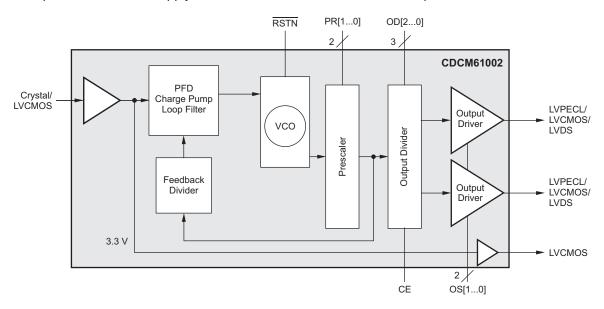


Figure 1. CDCM61002 Block Diagram

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#### AVAILABLE OPTIONS(1)

T <sub>A</sub>	PACKAGED DEVICES	FEATURES <sup>(2)</sup>
40°C to 105°C	CDCM61002RHBT	32-pin QFN (RHB) package, small tape and reel
-40°C to +85°C	CDCM61002RHBR	32-pin QFN (RHB) package, tape and reel

- (1) For the most current specifications and package information, see the Package Option Addendum located at the end of this data sheet or refer to our web site at www.ti.com.
- (2) These packages conform to Lead (Pb)-free and green manufacturing specifications. Additional details including specific material contentcan be accessed at www.ti.com/leadfree. GREEN: TI defines Green to mean Lead (Pb)-Free and in addition, uses less package materials that do not contain halogens, including bromine (Br), or antimony (Sb) above 0.1% of total product weight. N/A: Not yet available Lead (Pb)-Free; for estimated conversion dates, go to www.ti.com/leadfree. Pb-FREE: TI defines Lead (Pb)-Free to mean RoHS compatible, including a lead concentration that does not exceed 0.1% of total product weight, and, if designed to be soldered, suitable for use in specified lead-free soldering processes.

# **ABSOLUTE MAXIMUM RATINGS**(1)

Over operating free-air temperature range (unless otherwise noted).

	PARAMETER	VALUE	UNIT
VCC_OUT, VCC_PLL1, VCC_PLL2, VCC_VCO, VCC_IN	Supply voltage range (2)	-0.5 to 4.6	٧
$V_{IN}$	Input voltage range (3)	$-0.5$ to (V <sub>CC_IN</sub> + 0.5)	V
V <sub>OUT</sub>	Output voltage range <sup>(3)</sup>	-0.5 to (V <sub>CC_OUT</sub> + 0.5)	٧
I <sub>IN</sub>	Input current	20	mA
I <sub>OUT</sub>	Output current	50	mA
T <sub>STG</sub>	Storage temperature range	-65 to +150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating condition* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All supply voltages must be supplied simultaneously.
- (3) Input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

#### RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted).

	PARAMETER	MIN	NOM	MAX	UNIT
V <sub>CC_OUT</sub>	Output supply voltage	3.0	3.30	3.60	V
V <sub>CC_PLL1</sub>	PLL supply voltage	3.0	3.30	3.60	V
V <sub>CC_PLL2</sub>	PLL supply voltage	3.0	3.30	3.60	V
V <sub>CC_VCO</sub>	On-chip VCO supply voltage	3.0	3.30	3.60	V
V <sub>CC_IN</sub>	Input supply voltage	3.0	3.30	3.60	V
T <sub>A</sub>	Ambient temperature	-40		+85	°C

## **DISSIPATION RATINGS**(1)(2)

		TEOT	VALUE	_
	PARAMETER	TEST CONDITIONS	4 × 4 VIAS ON PAD	UNIT
$\theta_{JA}$	Thermal resistance, junction-to-ambient	0 LFM	35	°C/W
$\theta_{JP}^{(3)}$	Thermal resistance, junction-to-pad		4	°C/W

- (1) The package thermal resistance is calculated in accordance with JESD 51 and JEDEC 2S2P (high-K board).
- (2) Connected to GND with nine thermal vias (0.3-mm diameter).
- (3) θ<sub>JP</sub> (junction-to-pad) is used for the QFN package, because the primary heat flow is from the junction to the GND pad of the QFN package.



#### **ELECTRICAL CHARACTERISTICS**

At  $V_{CC}$  = 3 V to 3.6 V and  $T_A$  = -40°C to +85°C, unless otherwise noted.

			CD			
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Control Pin	LVCMOS Input Characteristics		*			
V <sub>IH</sub>	Input high voltage		0.6V <sub>CC</sub>			V
V <sub>IL</sub>	Input low voltage				0.4V <sub>CC</sub>	V
I <sub>IH</sub>	Input high current	$V_{CC} = 3.6 \text{ V}, V_{IL} = 0 \text{ V}$			200	μA
I <sub>IL</sub>	Input low current	V <sub>CC</sub> = 3 V, V <sub>IH</sub> = 3.6 V			-200	μA
LVCMOS O	utput Characteristics <sup>(1)</sup> (See Figur	e 9 and Figure 10)	-			
f <sub>OSC_OUT</sub>	Bypass output frequency		21.875		28.47	MHz
f <sub>OUT</sub>	Output frequency		43.75		250	MHz
V <sub>OH</sub>	Output high voltage	$V_{CC}$ = min to max, $I_{OH}$ = -100 $\mu$ A	V <sub>CC</sub> -0.5			V
V <sub>OL</sub>	Output low voltage	$V_{CC}$ = min to max, $I_{OL}$ = 100 $\mu$ A			0.3	V
t <sub>RJIT</sub>	RMS phase jitter	250 MHz (10 kHz to 20 MHz)			0.85	ps, RMS
t <sub>SLEW-RATE</sub>	Output rise/fall slew rate	20% to 80%	2.4			V/ns
ODC	Output duty cycle		45%		55%	
t <sub>SKEW</sub>	Skew between outputs				50	ps
I <sub>CC</sub> , LVCMOS	Device current, LVCMOS	$f_{IN}$ = 25 MHz, $f_{OUT}$ = 250 MHz, $C_L$ = 5 pF		120	140	mA
LVPECL Ou	tput Characteristics <sup>(2)</sup> (See Figure	e 11 and Figure 12)	<u> </u>			
f <sub>OUT</sub>	Output frequency		43.75		683.264	MHz
V <sub>OH</sub>	Output high voltage		V <sub>CC</sub> -1.18		V <sub>CC</sub> -0.73	V
V <sub>OL</sub>	Output low voltage		V <sub>CC</sub> –2		V <sub>CC</sub> -1.55	V
V <sub>OD</sub>	Differential output voltage		0.6		1.23	V
t <sub>RJIT</sub>	RMS phase jitter	625 MHz (10 kHz to 20 MHz)			0.77	ps, RMS
t <sub>R</sub> /t <sub>F</sub>	Output rise/fall time	20% to 80%			175	ps
ODC	Output duty cycle		45%		55%	
t <sub>SKEW</sub>	Skew between outputs				20	ps
I <sub>CC</sub> , LVPECL	Device current, LVPECL	f <sub>IN</sub> = 25 MHz, f <sub>OUT</sub> = 625 MHz		126	144	mA
LVDS Outpo	ut Characteristics <sup>(3)</sup> (See Figure 1	3 and Figure 14)	•			
f <sub>OUT</sub>	Output frequency		43.75		683.264	MHz
V <sub>OD</sub>	Differential output voltage		0.247		0.454	V
$\Delta V_{OD}$	V <sub>DD</sub> magnitude change				50	mV
Vos	Common-mode voltage		1.125		1.375	V
$\Delta V_{OS}$	V <sub>OS</sub> magnitude change				50	mV
t <sub>RJIT</sub>	RMS phase jitter	625 MHz (10 kHz to 20 MHz)			0.73	ps, RMS
t <sub>R</sub> /t <sub>F</sub>	Output rise/fall time	20% to 80%			255	ps
ODC	Output duty cycle		45%		55%	
t <sub>SKEW</sub>	Skew between outputs				30	ps
I <sub>CC</sub> , LVDS	Device current, LVDS	f <sub>IN</sub> = 25 MHz, f <sub>OUT</sub> = 625 MHz		110	125	

<sup>(1)</sup> Figure 9 and Figure 10 show dc and ac test setups, respectively. Jitter measurements made using 25-MHz quartz crystal in.

Figure 11 and Figure 12 show dc and ac test setups, respectively. Jitter measurements made using 25-MHz quartz crystal in. Figure 13 and Figure 14 show dc and ac test setups, respectively. Jitter measurements made using 25-MHz quartz crystal in.

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## TYPICAL OUTPUT PHASE NOISE CHARACTERISTICS

Over operating free-air temperature range (unless otherwise noted).

			CDC	M61002		
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
250-MHz L	VCMOS Output <sup>(1)</sup> (see Figure 10)	-				
phn <sub>100</sub>	Phase noise at 100-Hz offset			-95		dBc/Hz
phn <sub>1k</sub>	Phase noise at 1-kHz offset			-110		dBc/Hz
phn <sub>10k</sub>	Phase noise at 10-kHz offset			-117		dBc/Hz
phn <sub>100k</sub>	Phase noise at 100-kHz offset			-120		dBc/Hz
phn <sub>1M</sub>	Phase noise at 1-MHz offset			-135		dBc/Hz
phn <sub>10M</sub>	Phase noise at 10-MHz offset			-148		dBc/Hz
phn <sub>20M</sub>	Phase noise at 20-MHz offset			-148		dBc/Hz
t <sub>RJIT</sub>	RMS phase jitter from 10 kHz to 20 MHz			544		fs, RMS
t <sub>PJIT</sub>	Total period jitter			27.4		ps, PP
t <sub>STARTUP</sub>	Start-up time, power supply ramp time of 1 ms, final frequency accuracy of ±10 ppm			2.25		ms
625-MHz LV	VPECL Output <sup>(2)</sup> (see Figure 12)					
phn <sub>100</sub>	Phase noise at 100-Hz offset			<del>-</del> 81		dBc/Hz
phn <sub>1k</sub>	Phase noise at 1-kHz offset			-101		dBc/Hz
phn <sub>10k</sub>	Phase noise at 10-kHz offset			-109		dBc/Hz
phn <sub>100k</sub>	Phase noise at 100-kHz offset			-112		dBc/Hz
phn <sub>1M</sub>	Phase noise at 1-MHz offset			-129		dBc/Hz
phn <sub>10M</sub>	Phase noise at 10-MHz offset			-146		dBc/Hz
phn <sub>20M</sub>	Phase noise at 20-MHz offset			-146		dBc/Hz
t <sub>RJIT</sub>	RMS phase jitter from 10 kHz to 20 MHz			509		fs, RMS
t <sub>PJIT</sub>	Total period jitter			26.9		ps, PP
t <sub>STARTUP</sub>	Start-up time, power supply ramp time of 1 ms, final frequency accuracy of ±10 ppm			2.25		ms
625-MHz LV	VDS Output <sup>(3)</sup> (see Figure 14)					
phn <sub>100</sub>	Phase noise at 100-Hz offset			-88		dBc/Hz
phn <sub>1k</sub>	Phase noise at 1-kHz offset			-102		dBc/Hz
phn <sub>10k</sub>	Phase noise at 10-kHz offset			-109		dBc/Hz
phn <sub>100k</sub>	Phase noise at 100-kHz offset			-112		dBc/Hz
phn <sub>1M</sub>	Phase noise at 1-MHz offset			-129		dBc/Hz
phn <sub>10M</sub>	Phase noise at 10-MHz offset			-146		dBc/Hz
phn <sub>20M</sub>	Phase noise at 20-MHz offset			-146		dBc/Hz
t <sub>RJIT</sub>	RMS phase jitter from 10 kHz to 20 MHz			510		fs, RMS
t <sub>PJIT</sub>	Total period jitter			27		ps, PP
t <sub>STARTUP</sub>	Start-up time, power supply ramp time of 1 ms, final frequency accuracy of ±10 ppm			2.25		ms

<sup>(1)</sup> Figure 10 shows test setup and uses 25-MHz quartz crystal in,  $V_{CC} = 3.3 \text{ V}$ , and  $T_A = +25^{\circ}\text{C}$ . (2) Figure 12 shows test setup and uses 25-MHz quartz crystal in,  $V_{CC} = 3.3 \text{ V}$ , and  $T_A = +25^{\circ}\text{C}$ . (3) Figure 14 shows test setup and uses 25-MHz quartz crystal,  $V_{CC} = 3.3 \text{ V}$ , and  $T_A = +25^{\circ}\text{C}$ .



# TYPICAL OUTPUT JITTER CHARACTERISTICS(1)

OUTPUT		LVCMOS OUTPUT		LVPEC	LVPECL OUTPUT		OUTPUT
FREQUENCY (MHz)	INPUT (MHz)	t <sub>RJIT</sub>	t <sub>PJIT</sub> (ps <sub>PP</sub> )	t <sub>RJIT</sub>	t <sub>PJIT</sub> (ps <sub>PP</sub> )	t <sub>RJIT</sub>	t <sub>PJIT</sub> (ps <sub>PP</sub> )
62.5	25	592	32.9	611	20.7	667	28.4
75	25	518	27.5	533	19.4	572	25.7
77.76	24.8832	506	29.2	526	20.9	567	26.9
100	25	507	24.5	510	20.7	533	26.5
106.25	26.5625	535	23.5	524	20.2	553	26.5
125	25	557	39.6	556	21.4	570	27.1
150	25	518	38.4	493	18.9	515	26.2
155.52	24.8832	498	36.9	486	19.8	502	26.7
156.25	25	510	37.7	503	20.7	518	26.5
159.375	26.5625	535	37.4	510	19.9	534	26.3
187.5	25	506	32.8	506	20.3	509	25.5
200	25	491	23.3	492	30	499	34.9
212.5	26.5625	520	47.8	509	30.8	530	37.3
250	25	544	27.4	541	21.4	550	27.5
311.04	24.8832			481	20.5	496	24.7
312.5	25			501	20.8	508	25.8
622.08	24.8832			492	27.2	500	27.2
625	25			515	26.9	509	27

<sup>(1)</sup> Figure 10, Figure 12, and Figure 14 show LVCMOS, LVPECL, and LVDS test setups (respectively) using appropriate quartz crystal in,  $V_{CC} = 3.3 \text{ V}$ , and  $T_A = +25^{\circ}\text{C}$ .



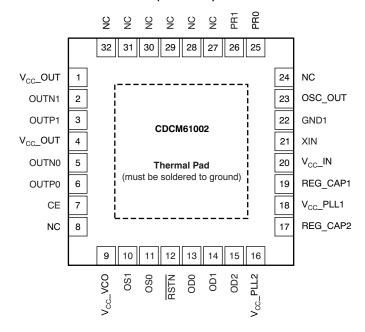
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#### **CRYSTAL CHARACTERISTICS**

PARAMETER	MINIMUM	TYPICAL	MAXIMUM	UNIT	
Mode of oscillation		Fundamental			
Frequency	21.875		28.47	MHz	
Equivalent series resistance (ESR)			50	Ω	
On-chip load capacitance		8	10	pF	
Drive level	0.1		1	mW	
Maximum shunt capacitance			7	pF	

## **DEVICE INFORMATION**

#### RHB PACKAGE QFN-32 (TOP VIEW)





## **PIN FUNCTIONS**

PIN				
NAME	PAD NO.	TYPE	DIRECTION <sup>(1)</sup>	DESCRIPTION
VCC_OUT	1, 4	Power		3.3-V supply for the output buffer
VCC_PLL1	18	Power		3.3-V supply for the PLL circuitry
VCC_PLL2	16	Power		3.3-V supply for the PLL circuitry
VCC_VCO	9	Power		3.3-V supply for the internal VCO
VCC_IN	20	Power		3.3-V supply for the input buffers
GND1	22	Ground		Additional ground for device. (GND1 shorted on-chip to GND)
GND	Pad	Ground		Ground is on thermal pad. See <i>Thermal Management</i>
XIN	21	Input		Parallel resonant crystal/LVCMOS input
OUTP0, OUTN0	6, 5	Output		Differential output pair or two single-ended outputs
OUTP1, OUTN1	3, 2	Output		Differential output pair or two single-ended outputs
OSC_OUT	23	Output		Bypass LVCMOS output
REG_CAP1	19	Output		Capacitor for internal regulator (connect to a 10-µF Y5V capacitor to GND)
REG_CAP2	17	Output		Capacitor for internal regulator (connect to a 10-µF Y5V capacitor to GND)
PR1, PR0	26, 25	Input	Pull-up	Prescaler and Feedback divider control pins (see Table 4)
OD2, OD1, OD0	15, 14, 13	Input	Pull-up	Output divider control pins (see Table 5)
OS1, OS0	10, 11	Input	Pull-up	Output type select control pin (see Table 6)
CE	7	Input	Pull-up	Chip enable control pin (see Table 7)
RSTN	12	Input	Pull-up	Device reset (active low) (see Table 8)
NC	8, 24, 27, 28, 29, 30, 31, 32			No connection

<sup>(1)</sup> Pull-up refes to internal input resistors; see Pin Characteristics for typical values.

# **Table 1. PIN CHARACTERISTICS**

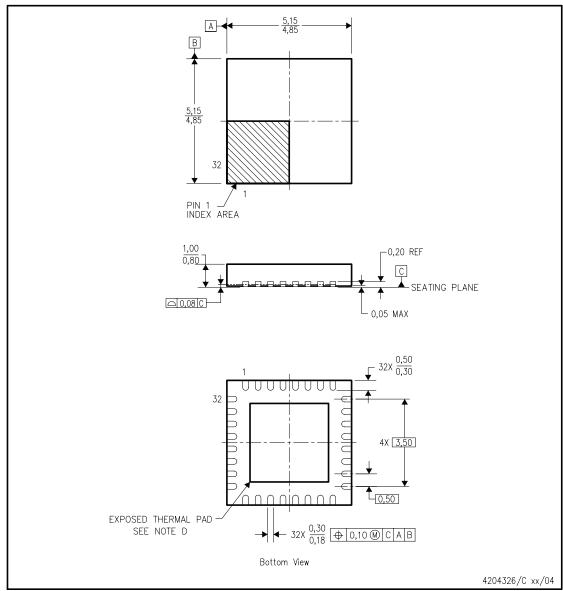
SYMBOL	PARAMETER	MIN	TYP	MAX	UNIT
C <sub>IN</sub>	Input capacitance		8	10	pF
R <sub>PULLUP</sub>	Input pull-up resistor		150		kΩ



#### **PACKAGE**

# RHB (S-PQFP-N32)

# PLASTIC QUAD FLATPACK



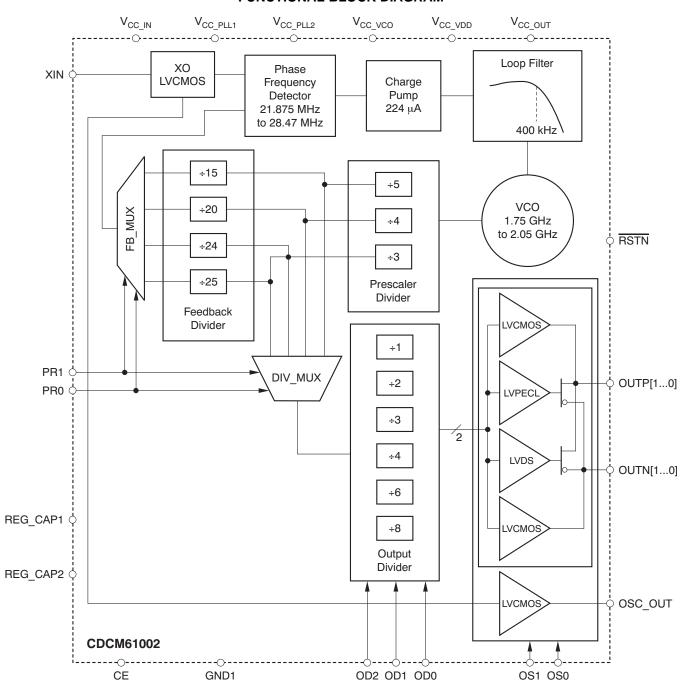
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No—Lead) Package configuration.
- D The Package thermal pad must be soldered to the board for thermal and mechanical performance. See product data sheet for details regarding the exposed thermal pad dimensions.
- E. Falls within JEDEC MO-220.

Figure 2. RHB Package



#### **FUNCTIONAL BLOCK DIAGRAM**





# **DEVICE CONFIGURATION**

# **Table 2. Common Configuration**

INPUT (MHz)	PRESCALER DIVIDER	FEEDBACK DIVIDER	VCO FREQUENCY (MHz)	OUTPUT DIVIDER	OUTPUT FREQUENCY (MHz)	APPLICATION
25	4	20	2000	8	62.5	GigE
24.75	3	24	1782	8	74.25	HDTV
25	3	24	1800	8	75	SATA
24.8832	3	25	1866.24	8	77.76	SONET
25	3	24	1800	6	100	PCI Express
26.5625	3	24	1912.5	6	106.25	Fibre Channel
25	4	20	2000	4	125	GigE
25	3	24	1800	4	150	SATA
24.8832	3	25	1866.24	4	155.52	SONET
25	3	25	1875	4	156.25	10 GigE
26.5625	3	24	1912.5	4	159.375	10-G Fibre Channel
25	5	15	1875	2	187.5	12 GigE
25	3	24	1800	3	200	PCI Express
26.5625	3	24	1912.5	3	212.5	4-G Fibre Channel
25	4	20	2000	2	250	GigE
24.8832	3	25	1866.24	2	311.04	SONET
25	3	25	1875	2	312.5	XGMII
24.8832	3	25	1866.24	1	622.08	SONET
25	3	25	1875	1	625	10 GigE

# **Table 3. Generic Configuration**

			o oomigaration		
INPUT FREQUENCY RANGE (MHz)	PRESCALER DIVIDER	FEEDBACK DIVIDER	VCO FREQUENCY RANGE (MHz)	OUTPUT DIVIDER	OUTPUT FREQUENCY RANGE (MHz)
21.875 to 25.62	4	20	1750 to 2050	8	54.6875 to 64.05
21.875 to 25.62	4	20	1750 to 2050	6	72.92 to 85.4
21.875 to 25.62	4	20	1750 to 2050	4	109.375 to 128.1
21.875 to 25.62	4	20	1750 to 2050	3	145.84 to 170.8
21.875 to 25.62	4	20	1750 to 2050	2	218.75 to 256.2
21.875 to 25.62	4	20	1750 to 2050	1	437.5 to 512.4
23.33 to 27.33	3	25	1750 to 2050	8	72.906 to 85.408
23.33 to 27.33	3	25	1750 to 2050	6	97.21 to 113.875
23.33 to 27.33	3	25	1750 to 2050	4	145.812 to 170.816
23.33 to 27.33	3	25	1750 to 2050	3	194.42 to 227.75
23.33 to 27.33	3	25	1750 to 2050	2	291.624 to 341.632
23.33 to 27.33	3	25	1750 to 2050	1	583.248 to 683.264
23.33 to 27.33	5	15	1750 to 2050	8	43.75 to 51.25
23.33 to 27.33	5	15	1750 to 2050	6	58.33 to 68.33
23.33 to 27.33	5	15	1750 to 2050	4	87.5 to 102.5
23.33 to 27.33	5	15	1750 to 2050	3	116.66 to 136.66
23.33 to 27.33	5	15	1750 to 2050	2	175 to 205
23.33 to 27.33	5	15	1750 to 2050	1	350 to 410
24.305 to 28.47	3	24	1750 to 2050	8	72.915 to 85.41
24.305 to 28.47	3	24	1750 to 2050	6	97.22 to 113.88
24.305 to 28.47	3	24	1750 to 2050	4	145.83 to 170.82



# **Table 3. Generic Configuration (continued)**

INPUT FREQUENCY RANGE (MHz)	PRESCALER DIVIDER	FEEDBACK DIVIDER	VCO FREQUENCY RANGE (MHz)	OUTPUT DIVIDER	OUTPUT FREQUENCY RANGE (MHz)
24.305 to 28.47	3	24	1750 to 2050	3	194.44 to 227.76
24.305 to 28.47	3	24	1750 to 2050	2	291.66 to 341.64
24.305 to 28.47	3	24	1750 to 2050	1	583.32 to 683.28

# **Table 4. Programmable Prescaler and Feedback Divider Settings**

CONTROL INPUTS		PRESCALER	FEEDBACK	PFD FREQUENCY		
PR1	PR0	DIVIDER	DIVIDER	MINIMUM	MAXIMUM	
0	0	3	24	24.305	28.47	
0	1	5	15	23.33	27.33	
1	0	3	25	23.33	27.33	
1	1	4	20	21.875	25.62	

## **Table 5. Programmable Output Divider**

	_	-				
	CONTROL INPUTS					
OD2	OD1	OD0	OUTPUT DIVIDER			
0	0	0	1			
0	0	1	2			
0	1	0	3			
0	1	1	4			
1	0	0	Reserved			
1	0	1	6			
1	1	0	Reserved			
1	1	1	8			

# **Table 6. Programmable Output Type**

CONTROL INPUTS		
OS1 OS0		OUTPUT TYPE
0	0	LVCMOS, OSC_OUT Off
0	1 LVDS, OSC_OUT Off	
1	0	LVPECL, OSC_OUT Off
1	1	LVPECL, OSC_OUT On

## Table 7. Output Enable

CONTROL INPUT	OPERATING	
CE	CONDITION	OUTPUT
0	Power Down	Hi-Z
1	Normal	Active

# Table 8. Reset

CONTROL INPUT RSTN	OPERATING CONDITION	OUTPUT
0	Device Reset	Hi-Z
0 → 1	PLL Recalibration	Hi-Z
1	Normal	Active



#### **TYPICAL CHARACTERISTICS**

Over operating free-air temperature range (unless otherwise noted).

# TYPICAL CURRENT CONSUMPTION FOR LVPECL OUTPUT vs OUTPUT FREQUENCY

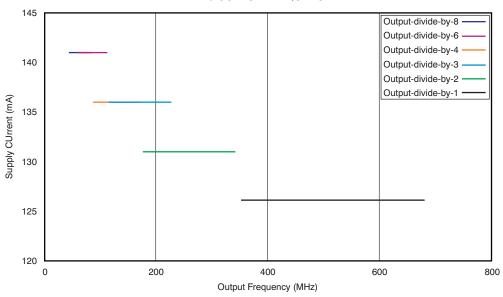


Figure 3.

# TYPICAL CURRENT CONSUMPTION FOR LVDS OUTPUT vs OUTPUT FREQUENCY

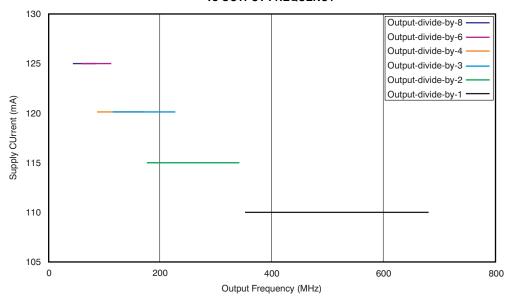


Figure 4.



# **TYPICAL CHARACTERISTICS (continued)**

Over operating free-air temperature range (unless otherwise noted).

# TYPICAL CURRENT CONSUMPTION FOR LYCMOS OUTPUT WITH 5-pF LOAD vs OUTPUT FREQUENCY

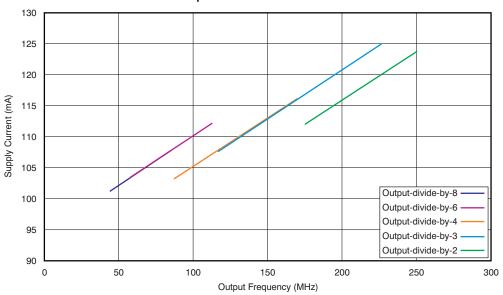


Figure 5.

# TYPICAL LVPECL DIFFERENTIAL OUTPUT VOLTAGE vs OUTPUT FREQUENCY

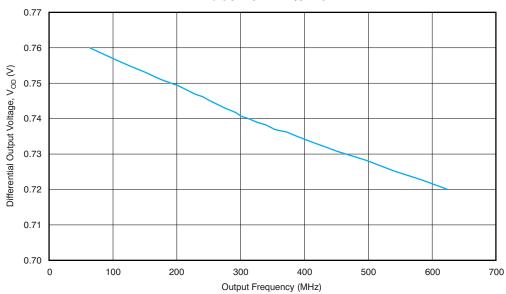


Figure 6.



# **TYPICAL CHARACTERISTICS (continued)**

Over operating free-air temperature range (unless otherwise noted).

# TYPICAL LVDS DIFFERENTIAL OUTPUT VOLTAGE vs OUTPUT FREQUENCY

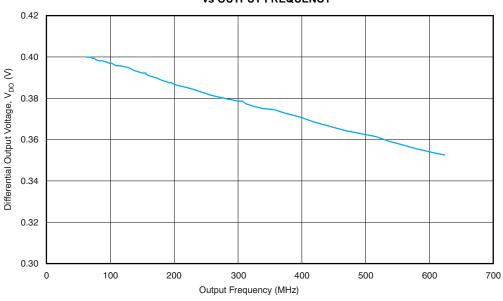


Figure 7.

# TYPICAL LVCMOS OUTPUT VOLTAGE WITH 5-pF LOAD vs OUTPUT FREQUENCY

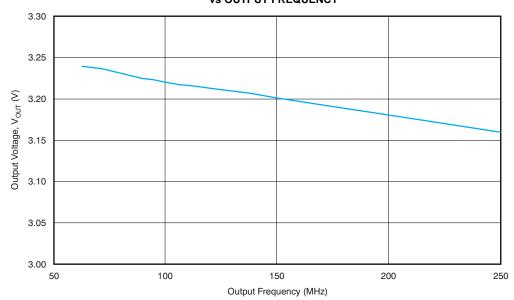


Figure 8.



#### **TEST CONFIGURATIONS**

This section describes the function of each block for the CDCM61002. Figure 9 through Figure 15 illustrate how the device should be set up for a variety of output configurations.

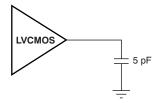


Figure 9. LVCMOS Output Loading During Device Test

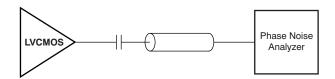


Figure 10. LVCMOS AC Configuration During Device Test

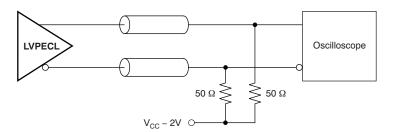


Figure 11. LVPECL DC Configuration During Device Test

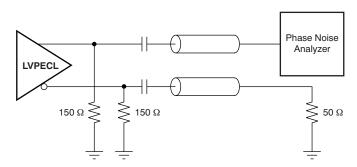


Figure 12. LVPECL AC Configuration During Device Test



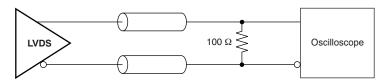


Figure 13. LVDS DC Configuration During Device Test

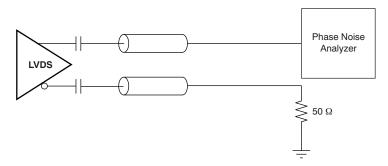


Figure 14. LVDS AC Configuration During Device Test

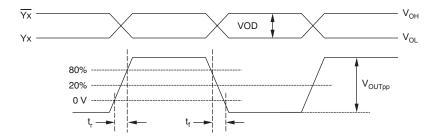


Figure 15. Output Voltage and Rise/Fall Times



#### **FUNCTIONAL DESCRIPTION**

# Phase-Locked Loop (PLL)

The CDCM61002 includes an on-chip PLL with an on-chip VCO. The PLL blocks consist of a crystal input interface, which can also accept an LVCMOS signal, a phase frequency detector (PFD), a charge pump, an on-chip loop filter, and prescaler and feedback dividers. Completing the CDCM61002 device are the output divider and universal output buffer.

The PLL is powered by on-chip, low-dropout (LDO) linear voltage regulators. The regulated supply network is partitioned such that the sensitive analog supplies are powered from separate LDOs rather than the digital supplies which use a separate LDO regulator. These LDOs provide isolation for the PLL from any noise in the external power-supply rail. The REG\_CAP1 and REG\_CAP2 pins should each be connected to ground by 10-µF capacitors to ensure stability.

# Configuring the PLL

The CDCM61002 permits PLL configurations to accommodate the various input and output frequencies listed in Table 2 and Table 3. These configurations are accomplished by setting the prescaler divider, feedback divider and output divider. The various dividers are managed by setting the device control pins as shown in Table 4 and Table 5.

### **Crystal Input Interface**

Fundamental mode is the recommended oscillation mode of operation for the input crystal and parallel resonance is the recommended type of circuit for the crystal.

A crystal load capacitance refers to all capacitances in the oscillator feedback loop. It is equal to the amount of capacitance seen between the terminals of the crystal in the circuit. For parallel resonant mode circuits, the correct load capacitance is necessary to ensure the oscillation of the crystal within the expected parameters.

The CDCM61002 implements an input crystal oscillator circuitry, known as the *Colpitts oscillator*, and requires one pad of the crystal to interface with the XIN pin; the other pad of the crystal is tied to ground. In this crystal interface, it is important to account for all sources of capacitance when calculating the correct value for the discrete capacitor component, C<sub>1</sub>, for a design.

The CDCM61002 has been characterized with 10-pF parallel resonant crystals. The input crystal oscillator stage in the CDCM61002 is designed to oscillate at the correct frequency for all parallel resonant crystals with low-pull capability and rated with a load capacitance that is equal to the sum of the onchip load capacitance at the XIN pin (10-pF), crystal stray capacitance, and board parasitic capacitance between the crystal and XIN pin.

The normalized frequency error of the crystal, as a result of load capacitance mismatch, can be calculated as Equation 2:

$$\frac{\Delta f}{f} = \frac{C_S}{2(C_{L,R} + C_O)} - \frac{C_S}{2(C_{L,A} + C_O)}$$
(2)

Where:

C<sub>S</sub> is the motional capacitance of the crystal,

C<sub>0</sub> is the shunt capacitance of the crystal,

C<sub>I,R</sub> is the rated load capacitance for the crystal,

C<sub>L,A</sub> is the actual load capacitance in the implemented PCB for the crystal,

 $\Delta f$  is the frequency error of the crystal,

and f is the rated frequency of the crystal.

The first three parameters can be obtained from the crystal vendor.

In order to minimize the frequency error of the crystal to meet application requirements, the difference between the rated load capacitance and the actual load capacitance should be minimized and a crystal with low-pull capability (low C<sub>S</sub>) should be used.



For example, if an application requires less than  $\pm 50$  ppm frequency error and a crystal with less than  $\pm 50$  ppm frequency tolerance is picked, the characteristics are as follows:  $C_0 = 7$  pF,  $C_S = 10$  fF, and  $C_{L,R} = 12$  pF. In order to meet the required frequency error, calculate  $C_{L,A}$  using Equation 2 to be 17 pF. Subtracting  $C_{L,R}$  from  $C_{L,A}$ , results in 5 pF; care must be taken during printed circuit board (PCB) layout with the crystal and the CDCM61002 to ensure that the sum of the crystal stray capacitance and board parisitic capacitance is less than the calculated 5 pF.

Good layout practices are fundamental to the correct operation and reliability of the oscillator. It is critical to locate the crystal components very close to the XIN pin to minimize routing distances. Long traces in the oscillator circuit are a very common source of problems. Do not route other signals across the oscillator circuit. Also, make sure power and high-frequency traces are routed as far away as possible to avoid crosstalk and noise coupling. Avoid the use of vias; if the routing becomes very complex, it is much better to use 0- $\Omega$  resistors as bridges to go over other signals. Vias in the oscillator circuit should only be used for connections to the ground plane. Do not share ground connections; instead, make a separate connection to ground for each component that requires grounding. If possible, place multiple vias in parallel for each connection to the ground plane. Especially in the Colpitts oscillator configuration, the oscillator is very sensitive to capacitance in parallel with the crystal. Therefore, the layout must be designed to minimize stray capacitance across the crystal to less than 5 pF total under all circumstances to ensure proper crystal oscillation. Be sure to take into account both PCB and crystal stray capacitance.

Table 9 lists several recommended crystals and the respective manufacturer of each.

MANUFACTURER	PART NUMBER
Vectron	VXC1-1133
Fox	218-3
Saronix	FP2650002

Table 9. Recommended Crystal Manufacturers

# **Phase Frequency Detector (PFD)**

The PFD takes inputs from the input interface and the feedback divider and produces an output that depends on the phase and frequency differences between the two inputs. The allowable range of frequencies at the PFD inputs is 21.875 MHz to 28.47 MHz.

#### **Charge Pump (CP)**

The charge pump is controlled by the PFD, which dictates either to pump up or down in order to charge or discharge the integrating section of the on-chip loop filter. The integrated and filtered charge pump current is then converted to a voltage that drives the control voltage node of the internal VCO through the on-chip loop filter. The charge pump current is preset to 224 µA and cannot be changed.

# **On-Chip PLL Loop Filter**

Figure 16 shows the on-chip active loop filter topology implemented in the device. This design corresponds to a PLL bandwidth of 400 kHz for a PFD in the range of 21.875 MHz to 28.47 MHz, and a charge pump current of  $224 \mu A$ .

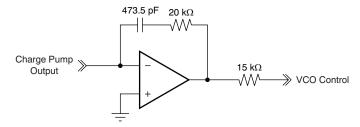


Figure 16. On-Chip PLL Loop Filter Topology



#### Prescaler Divider and Feedback Divider

The VCO output is routed to the prescaler divider and then to the feedback divider. The prescaler divider and feedback divider are set in tandem with each other, according to the control pin settings given in Table 4. The allowable combinations of the two dividers ensure that the VCO frequency and the PFD frequency are within the specified limits.

## **On-Chip VCO**

The CDCM61002 includes an on-chip, LC oscillator-based VCO with low phase noise covering a frequency range of 1.75 GHz to 2.05 GHz. The VCO must be calibrated to ensure proper operation over the valid device operating conditions. This calibration requires that the PLL be set up properly to lock the PLL loop and that the reference clock input be present. During the first device initialization after power-up, which occurs after the Power-On-Reset is released (2.64 V or lower, over valid device operating conditions) or a device reset with the RSTN pin, a VCO calibration sequence is initiated after 16,384 × Reference Input Clock Cycles. The VCO calibration then takes about 20 µs over the allowable range of the reference clock input.

The VCO calib<u>ration</u> can also be reinitiated with a pulse on the RSTN pin at any time after POR is released on power-up; the RSTN pulse must be at least 100 ns wide

For proper device operation, the reference input must be stable at the start of VCO calibration. Since inputs from crystals or crystal oscillators can typically take up to 1-2ms to be stable, it is recommended to establish circuitry on the RSTN pin that ensures device initialization including VCO calibration after a delay of greater than 5ms compared to the power up ramp, as shown in Figure 17. A possible implementation of the delay circuitry on the RSTN pin would be a 47nF capacitor to GND, and this in tandem with the  $150k\Omega$  on-chip pull-up resistor ensures the appropriate delay. The CE pin has an internal  $150k\Omega$  pull-up resistor and can be left unconnected or pulled to high for proper device operation.

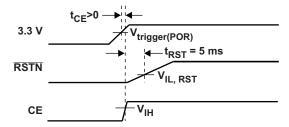


Figure 17. Suggested Timing Recommendations

### LVCMOS INPUT INTERFACE

Alternately, the CDCM61002 can be operated with an external ac-coupled 2.5-V LVCMOS or dc-coupled 3.3-V LVCMOS reference input applied to the XIN pin. For proper operation, the LVCMOS reference should be available and fairly stable by the time the power supply voltages or the RSTN pin voltage on the CDCM61002 reaches 2.27 V. See the application report SCAA111, available for download at ti.com, for more details about the LVCMOS input interface to the CDCM61002.

#### **Output Divider**

The output from the prescaler divider is also routed to the output divider. The output divider can be set with control pins according to Table 5.

## **Output Buffer**

Each output buffer can be set to LVPECL or LVDS or 2x LVCMOS, according to Table 6. OSC\_OUT is an LVCMOS output that can be used to monitor proper loading of the input crystal in order to achieve the necessary crystal frequency with the least error. The OSC\_OUT turns on as soon as power is available and remains on during deviec calibration. The output buffers are disabled during VCO calibration and are enabled only after calibration is complete.

The output buffers on the CDCM61002 can also be disabled, along with other sections of the device, using the CE pin according to Table 7.



#### **APPLICATION INFORMATION**

# **Start-up Time Estimation**

The CDCM61002 startup time can be estimated based on the parameters defined in Table 10 and graphically shown in Figure 18.

**Table 10. Start-up Time Dependencies** 

PARAMETER	DEFINITION	DESCRIPTION	FORMULA/METHOD OF DETERMINATION
t <sub>REF</sub>	Reference clock period	The reciprocal of the applied reference frequency in seconds.	$t_{REF} = \frac{1}{f_{REF}}$
t <sub>pul</sub>	Power-up time (low limit)	Power-supply rise time to low limit of Power On Reset (POR) trip point	Time required for power supply to ramp to 2.27 V
t <sub>puh</sub>	Power-up time (high limit)	Power supply rise time to high limit of POR trip point	Time required for power supply to ramp to 2.64 V
t <sub>rsu</sub>	Reference start-up time	After POR releases, the Colpits oscillator is enabled. This start-up time is required for the oscillator to generate the requisite signal levels for the delay block to be clocked by the reference input.	500 μs best-case and 800 μs worst-case
t <sub>delay</sub>	Delay time Internal delay time greference clock. This the reference oscillate		t <sub>delay</sub> = 16384 × t <sub>ref</sub>
t <sub>VCO_CAL</sub>	VCO calibration time	VCO Calibration Time generated from the reference clock. This process selects the operating point for the VCO based on the PLL settings.	t <sub>VCO_CAL</sub> = 550 × t <sub>ref</sub>
t <sub>PLL_LOCK</sub>	PLL lock time	Time required for PLL to lock within ±10 ppm of f <sub>REF</sub>	Based on the 400-kHz loop bandwidth, the PLL settles in 5τ or 12.5 μs.

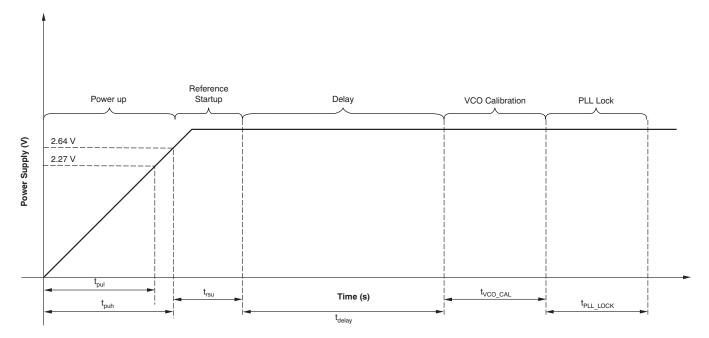


Figure 18. Start-up Time Dependencies



The CDCM61002 start-up time limits, t<sub>MAX</sub> and t<sub>MIN</sub>, can be calculated as follows:

$$t_{MAX} = t_{puh} + t_{rsu} + t_{delay} + t_{VCO\_CAL} + t_{PLL\_LOCK}$$
  
 $t_{MIN} = t_{pul} + t_{rsu} + t_{delay} + t_{VCO\_CAL} + t_{PLL\_LOCK}$ 

#### **Power Considerations**

As a result of the different possible configurations of the CDCM61002, Table 11 is intended to provide enough information on the estimated current consumption of the device. Unless otherwise noted,  $V_{CC} = 3.3 \text{ V}$  and  $T_A = +25^{\circ}\text{C}$ .

**Table 11. Estimated Block Power Consumption** 

вьоск	CONDITION	CURRENT CONSUMPTION (mA)	IN-DEVICE POWER DISSIPATION (mW)	EXTERNAL RESISTOR POWER DISSIPATION (mW)
Entire device, core current	Output off, no termination resistors 65 214.5			
	LVPECL output, active mode	28	42.4	50
	LVCMOS output pair, static	4.5	14.85	
Output buffer	LVCMOS output pair, transient, 'C <sub>L</sub> ' load, 'f' MHz output frequency	$V \times f_{OUT} \times (C_L + 20 \times 10^{-12}) \times 10^3$	$V^2 \times f_{OUT} \times (C_L + 20 \times 10^{-12}) \times 10^3$	
	LVDS output, active mode	20	66	
	Divide enabled, divide = 1	5	16.5	
Divide circuitm	Divide enabled, divide = 2	10	33	
Divide circuitry	Divide enabled, divide = 3, 4	15	49.5	
	Divide enabled, divide = 6, 8	20	66	

From Table 11, the current consumption can be calculated for any configuration. For example, the current for the entire device with one LVPECL output in active mode can be calculated by adding up the following blocks: core current, LVPECL output buffer current, and the divide circuitry current. The overall in-device power consumption can also be calculated by summing the in-device power dissipated in each of these blocks.

As an example scenario, let us consider the use case of a crystal input frequency of 25 MHz and device output frequency of 312.5 MHz in LVPECL mode. For this case, the typical overall power dissipation can be calculated as:

$$3.3 \text{ V} \times (65 + 2 \times 28 + 10) \text{ mA} = 432.3 \text{ mW}$$

Because the LVPECL output has external resistors and the power dissipated by these resistors is 50 mW, the typical overall in-device power dissipation is:

$$432.3 \text{ mW} - 2 \times 50 \text{ mW} = 332.3 \text{ mW}$$

When the LVPECL output is active, the average voltage is approximately 1.9 V on each output as calculated from the LVPECL  $V_{OH}$  and  $V_{OL}$  specifications. Therefore, the power dissipated in each emitter resistor is approximately  $(1.9 \text{ V})^2/150\Omega = 25 \text{ mW}$ .

When the LVCMOS output is active and drives a load capacitance, C<sub>L</sub>, the overall LVCMOS output current consumption is the sum of a static pre-driver current and a dynamic switching current (which is a function of the output frequency and the load capacitance).

Let us consider another use case of a crystal input frequency of 26.5625 MHz and device output frequency of 212.5 MHz in LVCMOS mode and driving a 5-pF load capacitance. For this case, the typical overall power dissipation can be calculated as:

$$3.3 \text{ V} \times (65 + 15 + 2 \times 21.4) \text{ mA} = 405.24 \text{ mW}$$

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#### **Thermal Management**

Power consumption of the CDCM61002 can be high enough to require attention to thermal management. For reliability and performance reasons, the die temperature should be limited to a maximum of +125°C. That is, as an estimate,  $T_A$  (ambient temperature) plus device power consumption times  $\theta_{JA}$  should not exceed +125°C.

The device package has an exposed pad that provides the primary heat removal path as well as an electrical grounding to the printed circuit board (PCB). To maximize the removal of heat from the package, a thermal land pattern including multiple vias to a ground plane must be incorporated on the PCB within the footprint of the package. The exposed pad must be soldered down to ensure adequate heat conduction out of the package. Check the mechanical data at the end of the data sheet for land and via pattern examples.

### **Power-Supply Filtering**

PLL-based frequency synthesizers are very sensitive to noise on the power supply, which can dramatically increase the jitter of the PLL. This characteristic is especially true for analog-based PLLs. Thus, it is essential to reduce noise from the system power supply, especially when jitter/phase noise is very critical to applications. A PLL would have attenuated jitter as a result of power-supply noise at frequencies beyond the PLL bandwidth because of attenuation by the loop response.

Filter capacitors are used to eliminate the low-frequency noise from the power supply, where the bypass capacitors provide the very low impedance path for high-frequency noise and guard the power-supply system against the induced fluctuations. These bypass capacitors also provide instantaneous current surges as required by the device and should have low equivalent series resistance (ESR). To properly use these bypass capacitors, they must be placed very close to the power-supply pins and laid out with short loops to minimize inductance. It is recommended to add as many high-frequency (for example, 0.1-µF) bypass capacitors as there are supply pins in the package.

The CDCM61002 power-supply requirements can be grouped into two sets: the analog supply line and the output/input supply line. The analog supply line consists of the following power-supply pins on the CDCM61002: VCC\_PLL1, VCC\_PLL2, and VCC\_VCO. These pins can be shorted together. The output/input supply line consists of the VCC\_OUT and the VCC\_IN power-supply pins on the CDCM61002. These pins can be shorted together. Inserting a ferrite bead between the analog supply line and the output/input supply line isolates the high-frequency switching noises generated by the device input and outputs, preventing them from leaking into the sensitive analog supply line. Choosing an appropriate ferrite bead with very low dc resistance is important because it is imperative to provide adequate isolation between the sensitive analog supply line and the other board supply lines, and to maintain a voltage at the analog power-supply pins of the CDCM61002 that is greater than the minimum voltage required for proper operation.



Figure 19 shows a general recommendation for decoupling the power supply.

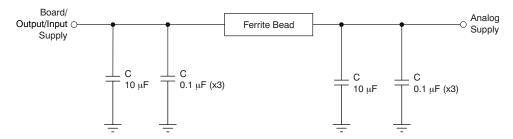


Figure 19. Recommended Power-Supply Decoupling

## **Output Termination**

The CDCM61002 is a 3.3-V clock driver with the following output options: LVPECL, LVDS, or LVCMOS.

#### **LVPECL Termination**

The CDCM61002 is an open emitter for LVPECL outputs. Therefore, proper biasing and termination are required to ensure correct operation of the device and to minimize signal integrity. The proper termination for LVPECL is  $50~\Omega$  to ( $V_{CC}$ –2) V, but this dc voltage is not readily available on most PCBs. Thus, a Thevenin equivalent circuit is worked out for the LVPECL termination in both direct-coupled (dc) and ac-coupled cases, as shown in Figure 20 and Figure 21. It is recommended to place all resistive components close to either the driver end or the receiver end. If the supply voltage of the driver and receiver are different, ac-coupling is required.

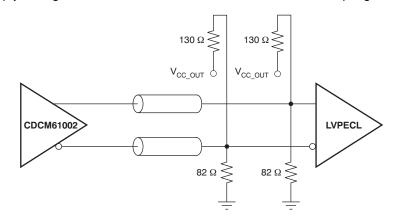


Figure 20. LVPECL Output DC Termination

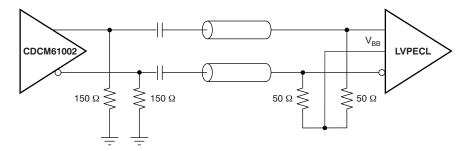


Figure 21. LVPECL Output AC Termination



#### **LVDS Termination**

The proper LVDS termination for signal integrity over two 50  $\Omega$  lines is 100  $\Omega$  between the outputs on the receiver end. Either dc-coupled termination or ac-coupled termination can be used for LVDS outputs, as shown in Figure 22 and Figure 23. It is recommended to place all resistive components close to either the driver end or the receiver end. If the supply voltage of the driver and the receiver are different, ac-coupling is required.

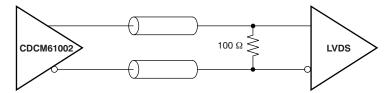


Figure 22. LVDS Output DC Termination

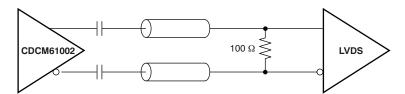


Figure 23. LVDS Output AC Termination

#### **LVCMOS Termination**

Series termination is a common technique used to maintain the signal integrity for LVCMOS drivers, if connected to a receiver with a high-impedance input with a pull-up or a pulldown resistor. For series termination, a series resistor ( $R_S$ ) is placed close to the driver, as shown in Figure 24. The sum of the driver impedance and  $R_S$  should be close to the transmission line impedance, which is usually 50  $\Omega$ . Because the LVCMOS driver in the CDCM61002 has an impedance of 30  $\Omega$ ,  $R_S$  is recommended to be 22  $\Omega$  to maintain proper signal integrity.

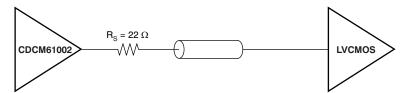


Figure 24. LVCMOS Output Termination



### Interfacing Between LVPECL and HCSL

Because the LVPECL common-mode voltage is different from the HCSL common-mode voltage, ac-coupled termination is used. The 150- $\Omega$  resistor ensures proper biasing of the CDCM61002 LVPECL output stage, while the 471- $\Omega$  and 56- $\Omega$  resistor network biases the HCSL receiver input stage, as shown in Figure 25.

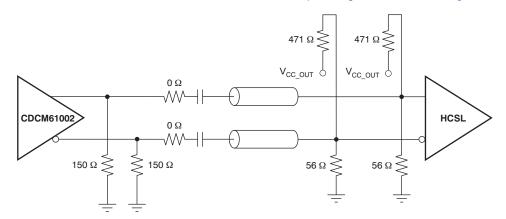


Figure 25. LVPECL to HCSL Interface



# **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision B (July, 2009) to Revision C	Page
•	Deleted references to Single-Ended and LVCMOS input throughout document	1
•	Deleted f <sub>IN</sub> , ΔV/ΔT, and DutyREF parameters from Electrical Characteristics	
<u>.</u>	Added LVCMOS Input Interface section	20
CI	hanges from Revision C (February 2010) to Revision D	Page
•	Added reference to LVCMOS reference in first Features bullet	1
•	Added reference to LVCMOS input in first paragraph of Description	1
•	Updated Figure 1	2
•	Changed name of Control Pin LVCMOS Input Characteristics section in Electrical Characteristics table	4
•	Added reference to LVCMOS input in XIN parameter of Pin Functions table	<mark>8</mark>
•	Changed description of Crystal Input Interface section	18
•	Changed description of LVCMOS Input Interface section	20
CI	hanges from Revision D (July 2010) to Revision E	Page
	Changed Note 1 of the Pin Functions table From: Pull-up and Pull-down refer toTo:Pull-up refers to	g
	Deleted R <sub>PULLDOWN</sub> from Table 1	
	Changed values in row 24.75 of Table 2	
	Changed the text of Configuring the PLL, deleted the last sentence	
•	Changed the On-Chip VCO section	
•	Changed the Output Buffer section	20
•	Changed the power dissipation equation From: 3.3 V × (65 + 2 × 28 + 10) mA = 429 mW To: 3.3 V × (65 + 2 × 28 + 10) mA = 432.3 mW	22
•	Changed the power dissipation equation From: 439 mW – 2 × 50 mW = 339 mW To: 432.3 mW – 2 × 50 mW = 332.3 mW	22
•	Deleted figure "Recommended PCB Layout for CDCM61001" from the Thermal Management section. Added text "See the mechanical data at the end of the data sheet"	23
CI	hanges from Revision E (March 2011) to Revision F	Page
•	Changed the On-Chip VCO section	20
•	Changed Figure 17	20
•	Moved the LVCMOS INPUT INTERFACE section prior to the Output Divider section	20

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#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CDCM61002RHBR	Active	Production	VQFN (RHB)   32	3000   LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	CDCM 61002
CDCM61002RHBR.B	Active	Production	VQFN (RHB)   32	3000   LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	CDCM 61002
CDCM61002RHBT	Active	Production	VQFN (RHB)   32	250   SMALL T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	CDCM 61002
CDCM61002RHBT.B	Active	Production	VQFN (RHB)   32	250   SMALL T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	CDCM 61002

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.



# **PACKAGE OPTION ADDENDUM**

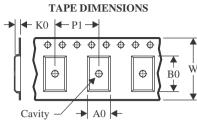
www.ti.com 11-Nov-2025

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

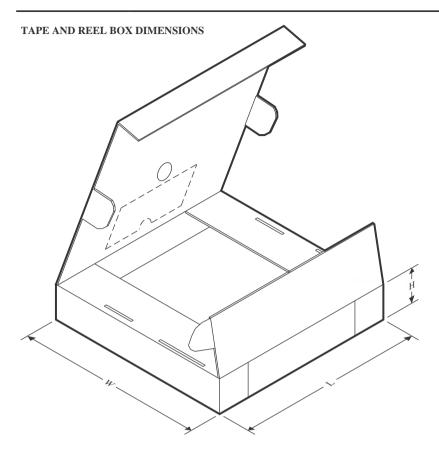
#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCM61002RHBR	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.5	8.0	12.0	Q2
CDCM61002RHBT	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.5	8.0	12.0	Q2

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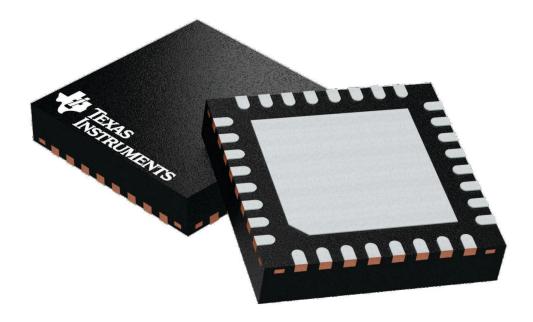


### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCM61002RHBR	VQFN	RHB	32	3000	353.0	353.0	32.0
CDCM61002RHBT	VQFN	RHB	32	250	213.0	191.0	35.0

5 x 5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD



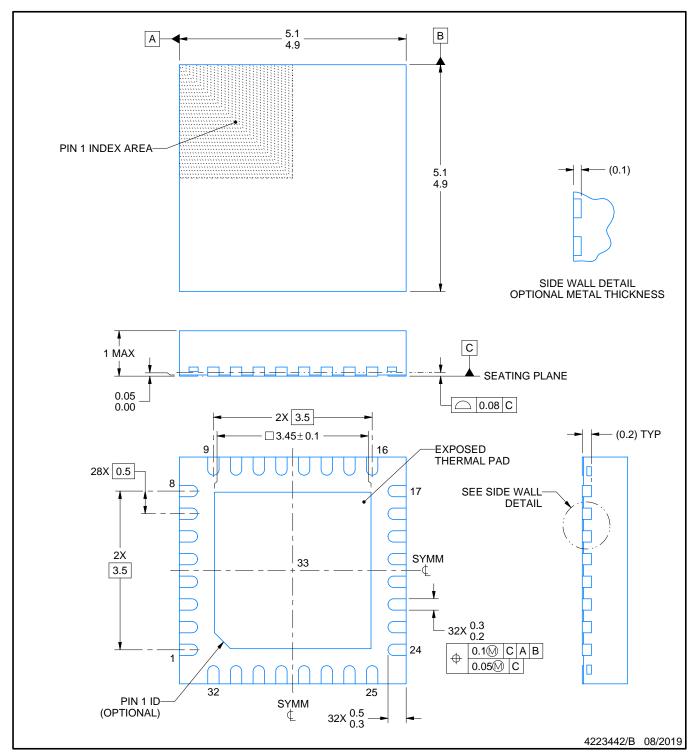
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4224745/A





PLASTIC QUAD FLATPACK - NO LEAD

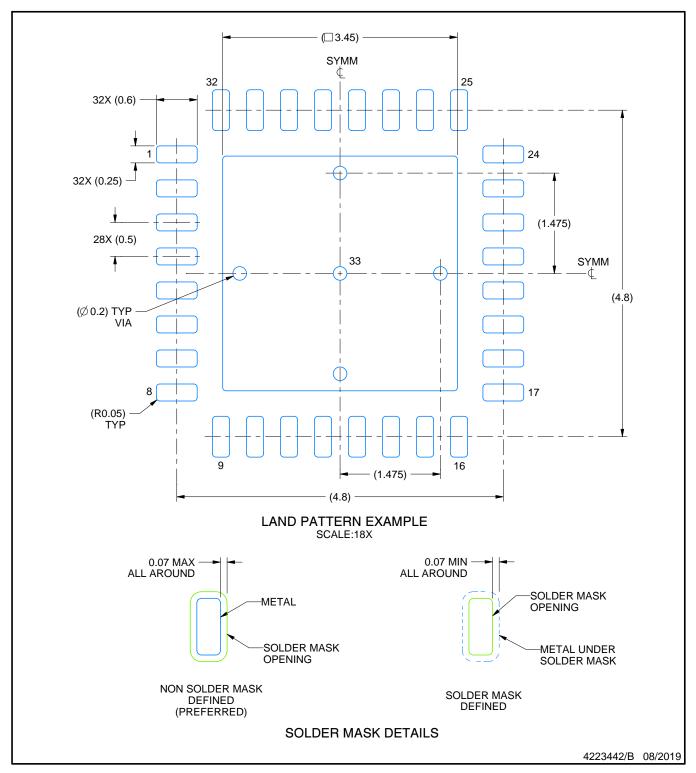


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

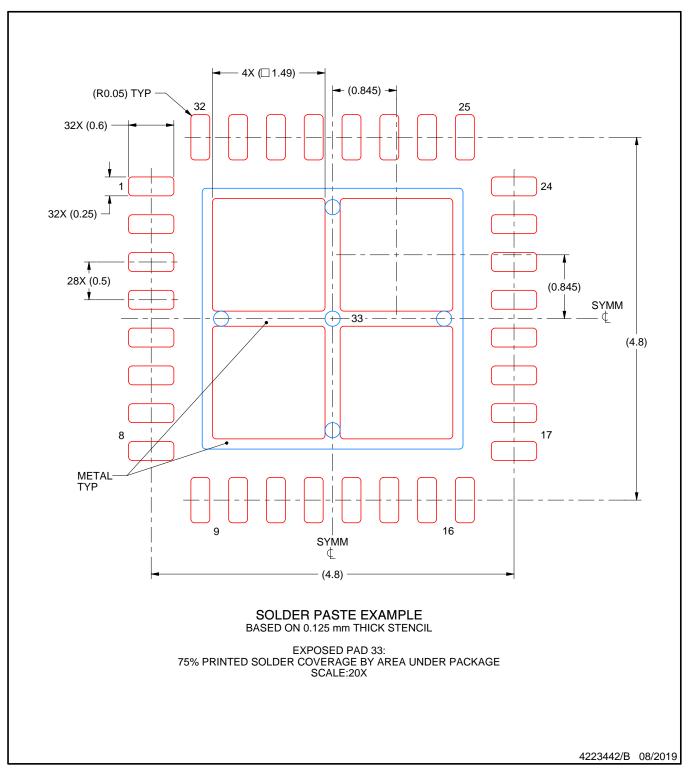


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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